

Quantum Physics of Nanostructures - Problem Set 4

Winter term 2014/2015

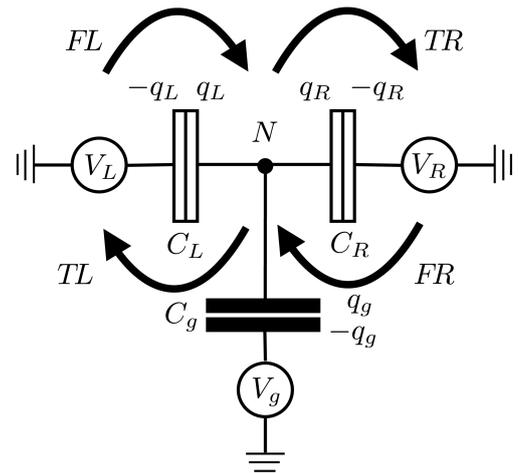
Due date: The problem set will be discussed Wednesday, 10.12.2014.

Internet: Course information and problem sets are available online at
http://www.uni-leipzig.de/~stp/QP_of_Nanostructures_WS1415.html.

9. Single Electron Transport

5+5+5+5 Points

In this problem, you will analyze the one-by-one transfer of electrons in a so-called single electron transistor (SET). The setup is sketched in Fig. 1. In contrast to the single electron box, the island is connected to a gate electrode with voltage V_g by a capacitance C_g . Employ the conventions shown in Fig. 1, which *differ* from those for the single electron box in the lecture. The induced charge is now defined as $q = C_L V_L + C_R V_R + C_g V_g$, while $q_L + q_R + q_g = eN$. This ensures, that for a symmetric ($C_R = C_L$) SET with an asymmetric bias, q does not depend on the bias voltage.



- (a) Derive an expression for the electrostatic energy E_{el} of the SET as a function of N and q .
- (b) Determine the energy differences ΔE_{FL} , ΔE_{TL} , ΔE_{FR} and ΔE_{TR} as functions of V_L and V_R , respectively, and the induced charge q . See Fig. 1 for the definition of the processes corresponding to the subscripts FL , TL , FR and TR .
- (c) For simplicity, assume symmetric capacitors $C_R = C_L$ and asymmetric bias voltage $V_R = -V_L = V/2$. Give the region in the $V - q$ plane corresponding to the one-by-one electron transfer sequence $N \rightarrow N + 1 \rightarrow N$ from right to left of the SET.
- (d) Determine the shape of Coulomb blockade diamonds in the $V - V_g$ plane for unequal capacitances $C_L \neq C_R$ assuming $V_L = 0$, $V_R = V$.

Fig. 1: Capacitance circuit for the single electron transistor with a total of N charges at the central island. The arrows correspond to the four different transfer processes of a single electron with respect to the central island: FL from left, TR to right, TL to left, FR from right.

Hints: In part (a), you should find $E_{el} = E_C(N - q/e)^2 + \text{const.}$, where the charging energy $E_C = e^2/2C_S$ is determined by the total capacitance $C_S = C_L + C_R + C_g$ and const. refers to terms independent of N . For part (b), remember that when adding (removing) an electron to (from) one of the electrodes, the corresponding contribution to the electrostatic energy is eV_i ($-eV_i$), where $i \in \{L, R, g\}$.